





### **Applications**

- Communications
- Electronic Warfare
- Test Instrumentation
- EMC Amplifier



### **Product Features**

Frequency Range: 2.5 to 6 GHz
P<sub>SAT</sub>: 46.5 dBm @ P<sub>IN</sub> = 26dBm, CW

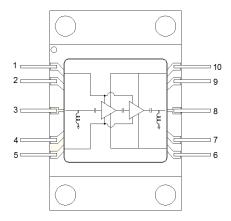
PAE: 36%

Small Signal Gain: 29 dB

• Bias:  $V_D = 30 \text{ V}$ ,  $I_{DQ} = 1.55 \text{ A}$ ,  $V_G = -2.5 \text{ V}$  Typical

• Dimensions: 11.4 x 17.3 x 3.0 mm.

## **Functional Block Diagram**



## **General Description**

TriQuint's TGA2576-2-FL is a wideband power amplifier fabricated on TriQuint's proven 0.25um GaN on SiC production technology. Operating from 2.5 to 6 GHz, the TGA2576-2-FL achieves 40W of saturated output power, greater than 36% power-added efficiency and 29dB small signal gain.

For ideal thermal management and handling, the TGA2576-2-FL is offered in a CuW-based flanged packaged and can operate in both CW and pulsed modes.

Both RF ports are fully matched to  $50\Omega$ , the TGA2576-2-FL is ideally suited to support a variety of commercial and defense related applications.

Lead-free and RoHS compliant

Evaluation Boards are available up on request.

## **Pin Configuration**

Pin No.	Symbol
1, 5	V <sub>G</sub>
2, 4, 7, 9	N/C
3	RF IN
6, 10	$V_{D}$
8	RF OUT

## **Ordering Information**

Part	<b>ECCN</b>	Description
TGA2576-2-FL	3A001.b.2.a	2.5 to 6GHz 40W GaN PA

Preliminary Datasheet: Rev A 01-8-15 © 2015 TriQuint

- 1 of 11 -

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# TGA2576-2-FL

## 2.5 to 6GHz 40W GaN Power Amplifier

### **Absolute Maximum Ratings**

Parameter	Value	
Drain Voltage (V <sub>D</sub> )	40 V	
Gate Voltage (V <sub>G</sub> )	−5 to 0 V	
Drain Current (I <sub>D</sub> )	5000 mA	
Gate Current (I <sub>G</sub> )	-18 to 35 mA	
Power Dissipation (P <sub>DISS</sub> )	93 W	
RF Input Power, CW, 50 Ω, T = 25°C	28 dBm	
Channel tremperature (T <sub>CH</sub> )	275°C	
Mounting Temperature (30 Seconds)	260°C	
Storage Temperature	-40 to 150°C	

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

## **Recommended Operating Conditions**

Parameter	Value		
Drain Voltage (V <sub>D</sub> )	30 V		
Drain Current (I <sub>DQ</sub> )	1550 mA		
Drain Current Under RF Drive (I <sub>D_DRIVE</sub> )	4300 mA		
Gate Voltage (V <sub>G</sub> )	-2.5 V		

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all operating conditions.

# **Electrical Specifications**

Test conditions unless otherwise noted:  $25^{\circ}$ C,  $V_D = 30$  V,  $I_{DQ} = 1550$  mA,  $V_G = -2.5$  V Typical, CW

Parameter	Min	Typical	Max	Units
Operational Frequency Range	2.5		6	GHz
Small Signal Gain		29		dB
Output Power at Saturation (Pin = 26 dBm)		46.5		dBm
Power-Added Efficiency (Pin = 26 dBm)		36 (Mid-band)		%
Gain Temperature Coefficient		-0.02		dB/°C
Power Temperature Coefficient		-0.02		dBm/°C



## **Thermal and Reliability Information**

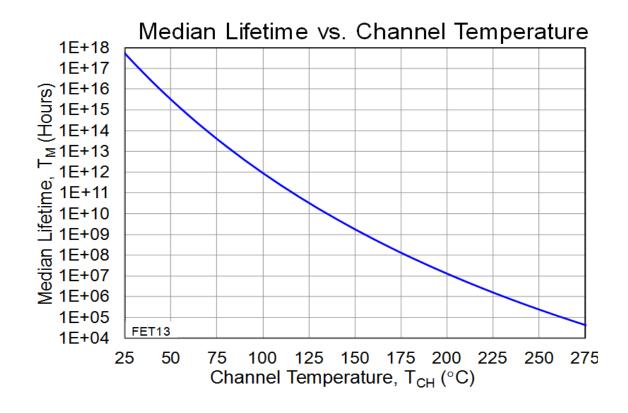
Parameter	Test Conditions	Value	Units
Thermal Resistance (θ <sub>JC</sub> ) <sup>(1)</sup>	T <sub>BASE</sub> = 85°C	2.04	°C/W
Channel Temperature Under RF Drive (T <sub>CH</sub> )	$V_D = 30 \text{ V}, I_{D \text{ Drive}} = 3600 \text{ mA}, P_{OUT} =$	224	°C
Median Lifetime Under RF Drive (T <sub>M</sub> )	46 dBm, P <sub>DISS</sub> = 68 W	1.69 x 10^6	Hours

#### Notes:

1. Measured from junction to center of package backside.

## **Median Lifetime**

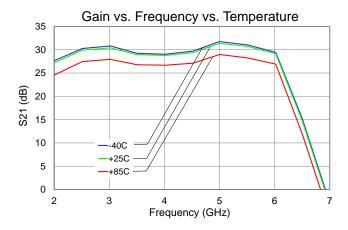
Test Conditions:  $V_D = 40V$ ; Failure Criteria is 10% reduction in  $I_{D\_MAX}$ 

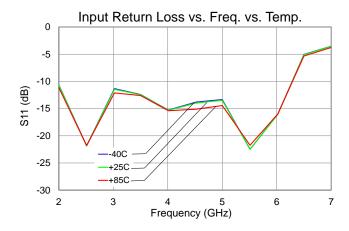


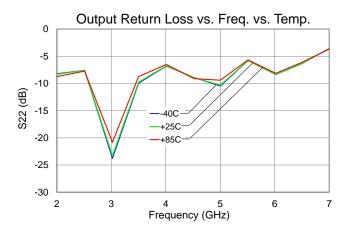


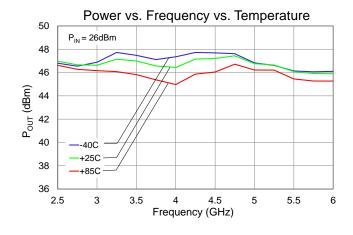
## **Typical Performance**

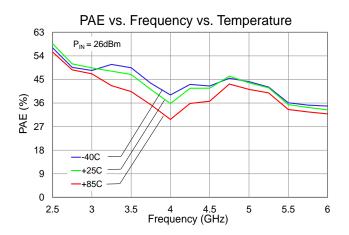
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW







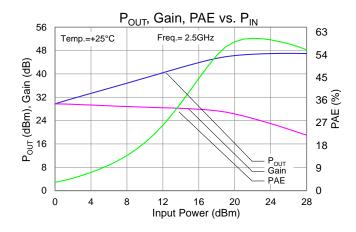


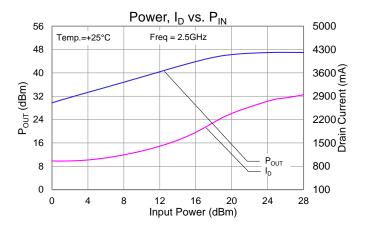


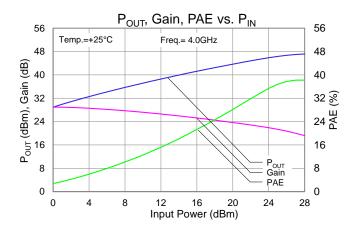


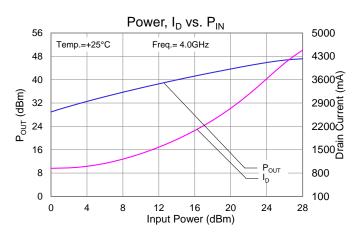
## **Typical Performance (con't.)**

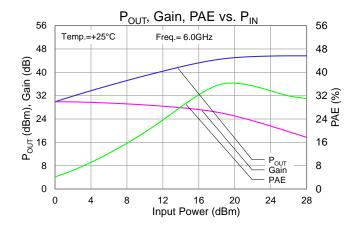
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW

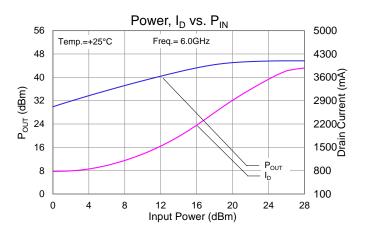








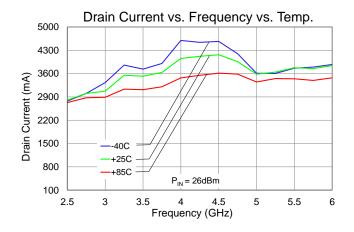


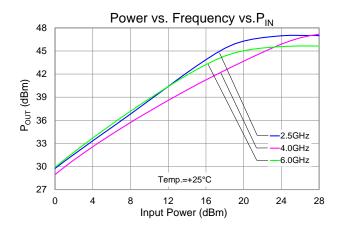




## **Typical Performance (con't.)**

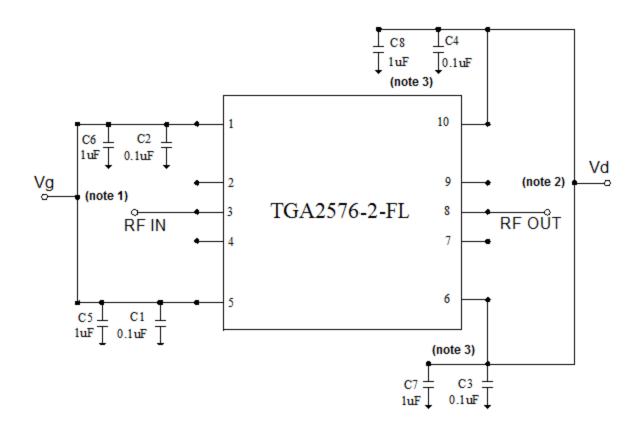
Conditions unless otherwise specified: VD = 30V, IDQ = 1.55A, VG = -2.5V Typical, CW







## **Application Circuit**



#### Notes:

- 1. V<sub>G</sub> must be biased from both sides (Pins 1 and 5).
- 2. V<sub>D</sub> must be biased from both sides (Pins 6 and 10).
- 3. Remove caps for pulsed drain operation.

## **Bias-up Procedure**

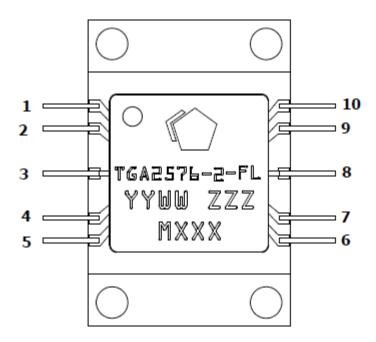
- 1. Set I<sub>D</sub> to 4.5A, I<sub>G</sub> to 20mA
- 2. V<sub>G</sub> set to -5.0V.
- 3.  $V_D$  set to +30V.
- 4. Adjust V<sub>G</sub> until I<sub>DQ</sub> ~ 1550 mA ( V<sub>G</sub> ~ -2.5V Typical)
- 5. Turn on RF supply.

### **Bias-down Procedure**

- 1. Turn off RF signal.
- 2. Reduce  $V_G$  to -5.0V. Ensure  $I_{DQ} \sim 0$  mA.
- 3. Set  $V_D$  to 0V.
- 4. Set V<sub>G</sub> to 0V.



## **Pin Description**



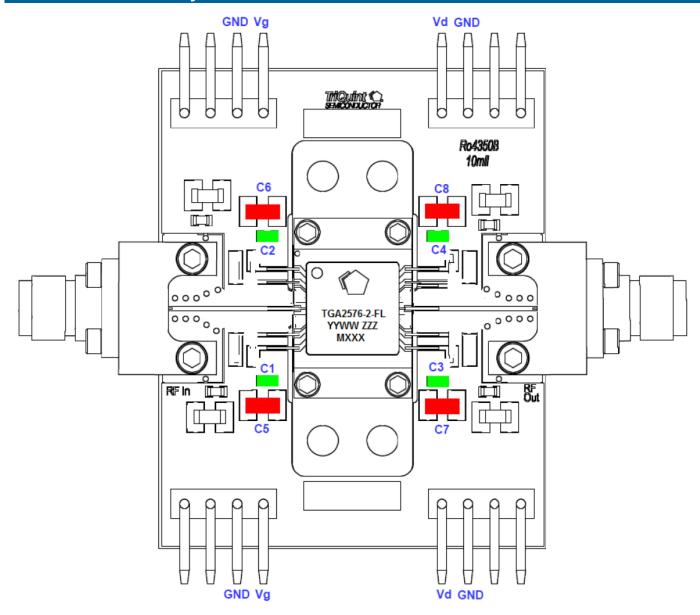
Pin	Symbol	Description
1, 5	VG	Gate voltage. (1)
2, 4, 7, 9	N/C	No internal connection; may be grounded or left open on PCB.
3	RF IN	Input; matched to 50 Ω; DC shorted to ground.
6, 10	V <sub>D</sub>	Bottom side Drain voltage. (2)
8	RF OUT	Output; matched to 50 Ω; DC shorted to ground.
	(Package Base)	RF and DC ground.

#### Notes:

- 1. Bias network is required; must be biased from both sides (Pins 1 and 5); see Application Circuit on page 7 as an example.
- 2. Bias network is required; must be biased from both sides (Pins 6 and 10); see Application Circuit on page 7 as an example.



## **Evaluation Board Layout**



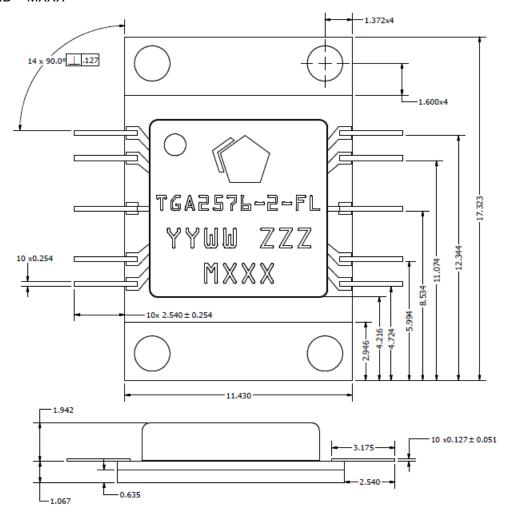
<b>Bill of Material</b>
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Reference Des.	Value	Description	Manuf.	Part Number
C1 – C4	0.1 µF	Cap, 0603, 50 V, 10%, X7R	Various	
C5 – C8	1 µF	Cap, 1206, 50 V, 10%, X7R	Various	



### Mechanical Information - Package Information and Dimensions

Marking: Part number – TGA2576-2-FL Year/week/lot code - YYWW ZZZ Batch ID – MXXX



#### Notes:

- 1. Unless specified otherwise, dimensions are in millimeters (mm).
- 2. Unless specified otherwise, tolerances are  $\pm$  0.127
- 3. Materials:

Package base: Copper Tungsten (CuW) composite
Package lid: LCD (liquid crystal polymer)
Package leads: Kovar, MIL I 23011C Class 1

Plating finish: Gold (Au) 1.27um minimum over Nickel (Ni) 2.54 to 8.89um

## **Assembly Notes**

- 1. 0-80 screws are recommended for mounting the TGA2576-2-FL to the board.
- 2. To improve the thermal and RF performance, we recommend the following:
  - a) Apply thermal compound or 4 mils indium shim between the package and the board.
  - b) Attach a heat sink to the bottom of the board and apply thermal compound or 4 mils indium shim between the heat sink and the board.
- 3. Apply solder to each pin of the TGA2576-2-FL.





### **Product Compliance Information**

### **ESD Sensitivity Ratings**



Caution! ESD-Sensitive Device

ESD Rating: Class 1B

Value: ≥500V and <1000V

Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

### **MSL** Rating

Level 3 at +260 °C convection reflow The part is rated Moisture Sensitivity Level 3 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

#### **ECCN**

US Department of Commerce: 3A001.b.2.a

## **Solderability**

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>0<sub>2</sub>) Free
- PFOS Free
- SVHC Free

### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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